



THE OFFICIAL DATE STAMP HEREON BY THE USPTO ACKNOWLEDGES RECEIPT OF THE FOLLOWING:

DATE: December 6, 2004 DOCKET: 90065.99R272/17732.6323
APPLICANT(S): Jifa Hao, et al.
SERIAL NO.: 09/654,845
FILED: September 1, 2000
FOR: POWER SEMICONDUCTOR DEVICE WITH HIGH AVALANCHE CAPABILITY
AND PROCESS FOR FORMING SAME

PAPERS ENCLOSED:

- .) Amendment Transmittal Letter (1 page);
- Amendment (12 pages);
- Certificate of First Class Mail;
-) Return Receipt Acknowledgment Postcard.